

Data Sheet March 29, 2007 FN6472.0

## 500MHz Rail-to-Rail Amplifiers

The 5962-0623501QPC, 5962-0623502QPC are fully DSCC SMD compliant parts and the SMD data sheets are available on the DSCC website

(http://www.dscc.dla.mil/programs/specfind/default.asp). The 5962-0623501QPC is electrically equivalent to the EL8102 and the 5962-0623502QPC is electrically equivalent to the EL8103, reference these data sheets for additional information. These parts are single rail-to-rail amplifiers with a -3dB bandwidth of 500MHz and slew rate of 600V/ $\mu s$ . Running off a very low 11mA supply current, the 5962-0623501QPC, 5962-0623502QPC also feature inputs that go to 0.15V below the  $V_{S^-}$  rail.

The 5962-0623501QPC includes a fast-acting disable/power-down circuit. With a 25ns disable and a 200ns enable, the 5962-0623501QPC is ideal for multiplexing applications.

The 5962-0623501QPC, 5962-0623502QPC are designed for a number of general purpose video, communication, instrumentation, and industrial applications. Both parts are available in 8 Ld SBDIP. All are specified for operation over the -55°C to +125°C temperature range.

## **Ordering Information**

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE	PKG. DWG.#
5962-0623501QPC	5962-0623 501QPC	-55 to +125	8 Ld SBDIP	D8.3
5962-0623502QPC	5962-0623 502QPC	-55 to +125	8 Ld SBDIP	D8.3

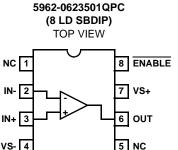
#### **Features**

- · 500MHz -3dB bandwidth
- 600V/µs slew rate
- Low supply current = 11mA
- Supplies from 3V to 5.0V
- · Rail-to-rail output
- Input to 0.15V below V<sub>S</sub>-
- Fast 25ns disable (5962-0623501QPC only)

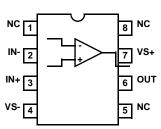
## **Applications**

- · Video amplifiers
- · Portable/hand-held products
- · Communications devices

### **Pinouts**



**5962-0623502QPC (8 LD SBDIP)** TOP VIEW



## 5962-0623501QPC, 5962-0623502QPC

## **Absolute Maximum Ratings** $(T_A = +25$ °C)

### **Thermal Information**

Supply Voltage from V <sub>S</sub> + to V <sub>S</sub>	Power Dissipation
Input Voltage	Storage Temperature
Differential Input Voltage2V	Ambient Operating Temperature
Continuous Output Current	Operating Junction Temperature

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$ 

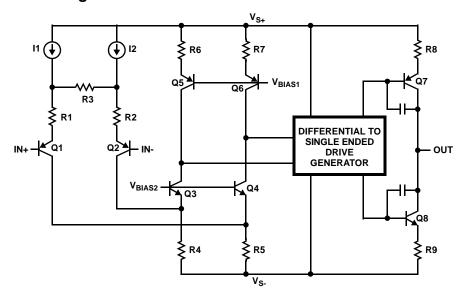
## **Electrical Specifications** $V_S$ + = 5V, $V_S$ - = GND, $T_A$ = +25°C, $V_{CM}$ = 2.5V, $R_L$ to 2.5V, $A_V$ = 1, Unless Otherwise Specified

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
INPUT CHARA	ACTERISTICS		I	1	1	"
R <sub>IN</sub>	Input Resistance	Common Mode		3.5		MΩ
C <sub>IN</sub>	Input Capacitance			0.5		pF
OUTPUT CHA	RACTERISTICS		I	1	1	1
R <sub>OUT</sub>	Output Resistance	A <sub>V</sub> = +1		30		mΩ
ENABLE (596	2-0623501QPC ONLY)		I	1	1	1
t <sub>EN</sub>	Enable Time			200		ns
t <sub>DS</sub>	Disable Time			25		ns
AC PERFORM	ANCE		I	1	1	1
BW	-3dB Bandwidth	$A_V = +1, R_F = 0\Omega, C_L = 5pF$		500		MHz
		$A_V = -1$ , $R_F = 1k\Omega$ , $C_L = 5pF$		140		MHz
		$A_V = +2$ , $R_F = 1k\Omega$ , $C_L = 5pF$		165		MHz
		$A_V = +10, R_F = 1k\Omega, C_L = 5pF$		18		MHz
BW	±0.1dB Bandwidth	$A_V = +1, R_F = 0\Omega, C_L = 5pF$		35		MHz
Peak	Peaking	$A_V = +1, R_L = 1k\Omega, C_L = 5pF$		1		dB
GBWP	Gain Bandwidth Product			200		MHz
PM	Phase Margin	$R_L = 1k\Omega$ , $C_L = 5pF$		55		0
SR	Slew Rate	$A_V = 2$ , $R_L = 100\Omega$ , $V_{OUT} = 0.5V$ to 4.5V		600		V/µs
t <sub>R</sub>	Rise Time	2.5V <sub>STEP</sub> , 20% to 80%		4		ns
t <sub>F</sub>	Fall Time	2.5V <sub>STEP</sub> , 20% to 80%		2		ns
os	Overshoot	200mV step		10		%
t <sub>PD</sub>	Propagation Delay	200mV step		1		ns
t <sub>S</sub>	0.1% Settling Time	200mV step		15		ns
dG	Differential Gain	$A_V = +2, R_F = 1k\Omega, R_L = 150\Omega$		0.01		%
dP	Differential Phase	$A_V = +2, R_F = 1k\Omega, R_L = 150\Omega$		0.01		0
e <sub>N</sub>	Input Noise Voltage	f = 10kHz		12		nV/√Hz
i <sub>N</sub> +	Positive Input Noise Current	f = 10kHz		1.7		pA/√Hz
i <sub>N</sub> -	Negative Input Noise Current	f = 10kHz		1.3		pA/√Hz

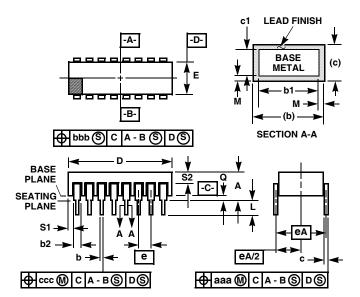
# Pin Descriptions

PART			
5962-0623501QPC	5962-0623502QPC	PIN NAME	FUNCTION
1, 5	1, 5, 8	NC	Not connected
2	2	IN-	Inverting input
3	3	IN+	Non-inverting input
4	4	VS-	Negative power supply
6	6	OUT	Amplifier output
7	7	VS+	Positive power supply
8		ENABLE	Enable and disable input

# Simplified Schematic Diagram



## Ceramic Dual-In-Line Metal Seal Packages (SBDIP)



#### NOTES:

- Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
- The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
- Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
- Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
- 5. Dimension Q shall be measured from the seating plane to the base plane.
- 6. Measure dimension S1 at all four corners.
- 7. Measure dimension S2 from the top of the ceramic body to the nearest metallization or lead.
- 8. N is the maximum number of terminal positions.
- 9. Braze fillets shall be concave.
- 10. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 11. Controlling dimension: INCH.

D8.3 MIL-STD-1835 CDIP2-T8 (D-4, CONFIGURATION C) 8 LEAD CERAMIC DUAL-IN-LINE METAL SEAL PACKAGE

	INCHES		MILLIM		
SYMBOL	MIN	MAX	MIN	MIN MAX	
Α	=	0.200	=	5.08	-
b	0.014	0.026	0.36	0.66	2
b1	0.014	0.023	0.36	0.58	3
b2	0.045	0.065	1.14	1.65	-
b3	0.023	0.045	0.58	1.14	4
С	0.008	0.018	0.20	0.46	2
c1	0.008	0.015	0.20	0.38	3
D	-	0.405	-	10.29	-
Е	0.220	0.310	5.59	7.87	-
е	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
eA/2	0.150 BSC		3.81 BSC		-
L	0.125	0.200	3.18 5.08		-
Q	0.015	0.060	0.38	1.52	5
S1	0.005	-	0.13	-	6
S2	0.005	-	0.13	-	7
α	90°	105°	90°	105°	-
aaa	-	0.015	-	0.38	-
bbb	-	0.030	-	0.76	-
ccc	-	0.010	-	0.25	-
М	-	0.0015	-	0.038	2
N	8		8		8

Rev. 0 4/94

FN6472.0

March 29, 2007

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